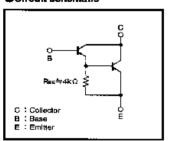
# Power Transistor (-40V, -2A)

## 2SB1183 / 2SB1239 / 2SB786F

### Features

- 1) Darlington connection for high DC current gain.
- 2 ) Built-in 4 k  $\Omega$  resistor between base and emitter.
- 3) Complements the 2SD1759/2SD1861/2SD947F.

### Circuit schematic



### ●Absolute maximum ratings (Ta=25℃)

Paren	Parameter		Limits	Ųnit
Collector-base voltage		Vœo	-40	V
Collector-emitter voltage		Voer	-40	٧
Emitter-base voltage		VERO	-5	٧
Collector current		1-	<b>-2</b>	A (DC)
Conector current		lc lc	-3	A (Pulse) #1
	2SB1183		1	W
	2561163		10	W (Tc=25°C)
Collector power	2SB1239	Pc	1	W *2
dissipation	2\$8786F	7	1.2	W
	236760	256/607	5	W(Tc=25℃)
Junction temperature		TJ	150	ع ا
Storage temperat	Storage temperature		-55~150	Ċ

- \*1 Sigle pulse Pw≕10me
- Packaging specifications and hre
- Printed circuit board 1.7mm thick, collector plating 1cm² or larger.

Туре	2881163	2SB1239	2SB786F
Package	CPT3	ATV	TO-126FP
ħÆ	1k~200k	1k~-	1k~-
Code	ΠL	T148	<u> </u>
Basic ordering unit (pleces)	2500	2500	1000

### ●Electrical characteristics (Ta=25℃)

Par	rameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base I	breakdown voltage	BVœo	-40		_	٧	lc=−50 μA
Collector-emitte	r breakdown voltage	BVCER	-40		_	٧	lc=-1mA , RBE=10kΩ
Emitter-base br	eakdown voltage	BVeec	-5	_	_	V	lE=-50 μA
Collector cutoff	current	lano	_	_	-1	μА	Vçe=~24V
Emitter cutoff cu	urrent	(EBO		_	-1	μА	V <sub>EB</sub> =-4V
Collector-emitte	r saturation voltage	Vole(sat)	_	_	-1.5	>	lc/le=+0.6A/-1.2mA
DC current	2SB1183	ħr∈	1000	_	20000		Vr=/Ic=-2V/-0.5A
transfer ratio	2SB1239,2SB786F	IIFE	1000				VOE/IC#2V/0.3A
Output capacita	nce	Çob	_	11		pF	<sup>1</sup> Vce=−10V , Ic=0A , f=1MHz

(96-126-B23)

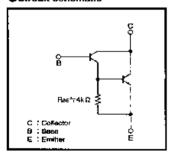
# Power Transistor (40V, 2A)

### 2SD1759 / 2SD1861 / 2SD947F

### Features

- 1) Darlington connection for high DC current gain.
- 2.) Built-in  $4k\Omega$  resistor between base and emitter.
- 3) Complements the 2SB1183/2SB1239/2SB786F.

### **●**Circuit schematic



### ●Absolute maximum ratings(Ta=25℃)

Parameter Collector-base voltage		Symbol	Limits	Unit
		Vсво	40	V
Collector-emitter	voltage	Vçeя	40	V(R <sub>BE</sub> =10kΩ)
Emitter-base volt	er-base voltage		5	V
Collector current			2	A (DC)
Collector correcti		l lc	3	A (Pulse) #1
	2SD1861		1	*2
Callagian	2SD1759	7 i	1	- w -
Collector power dissipation	2501759	l Pc	10	W(Tc=25°C)
210012441011	00D017E	7 i	1.2	ł w
	2509475	2SD947F	5	W(Tc=25°C)
Junction temperature		Tj	150	ť
Storage temperat	ture	Telg	<del>-55</del> ~150	τ

\*1 Sigle pulse Pw=10ms

\*2 Printed circuit board 1.7mm thick,

### ●Packaging specifications and hre

Туре	23D1759	2SD1881	2SD947F
Package	СРТЗ	ΑTV	TO-126FP
hee .	1k~200k	1k	1k~
Code	π.	TV2	_
Basic ordering unit (oteces)	9500	2600	1000

### ●Electrical characteristics (Ta=25℃)

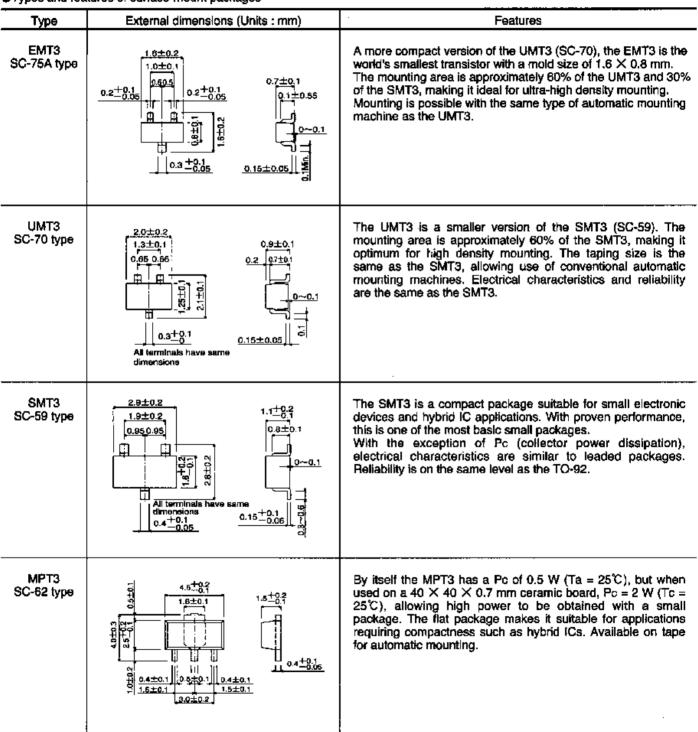
Par	ameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base b	reakdown voltege	BVrso	40		_	٧	Ic=50 μA
Collector-emitter	breakdown voltage	BVcso	40	_	_	٧	lc=1mA , Rec=10kΩ
Emitter-base bre	akdown vollage	BVeso	5	<u> </u>	_	ν	Ie=50 μA
Collector cutoff of	current	Iceo		_	1	μА	Vcs=24V
Emitter cutoff cu	ment	IFRO	_	<u> </u>	†	μA	V <sub>EB</sub> =4V
Collector-emitter	r saturation vollage	VCE(eet)			1.5	v	Ic/Is=0.6mA/1.2mA
DC current	2SD1759		1000	_	20000		II B claim 54
transfer ratio	2SD1861,2SD947F	ħÆ	1000				Vce/tc=3V/0.5A
Output capacitat	nce	Cob	_	11		pΕ	Vcs=10V , IE=0A , f=1MHz

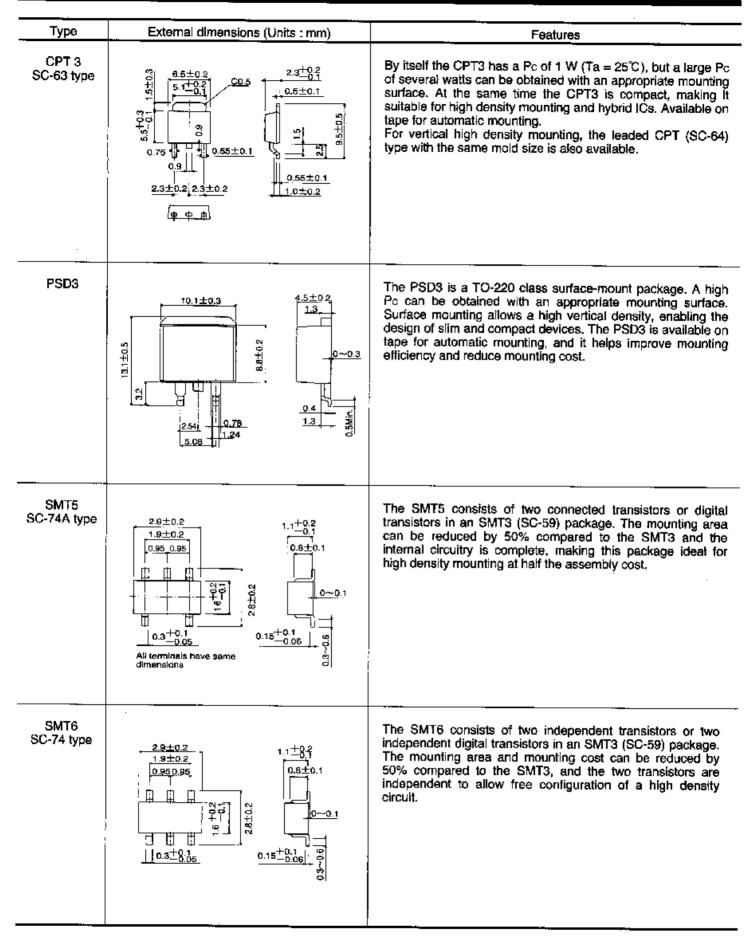
Transistors Packages

## **Packages**

ROHM has been manufacturing transistors since 1975. In the development of products, we constantly strive to anticipate the needs of our customers. Regarding packages, the demands of the market for compactness, low power consumption, low power dissipation and automatic mounting support are becoming ever greater, and we are strengthening our product development system to meet these needs.

Types and features of surface-mount packages



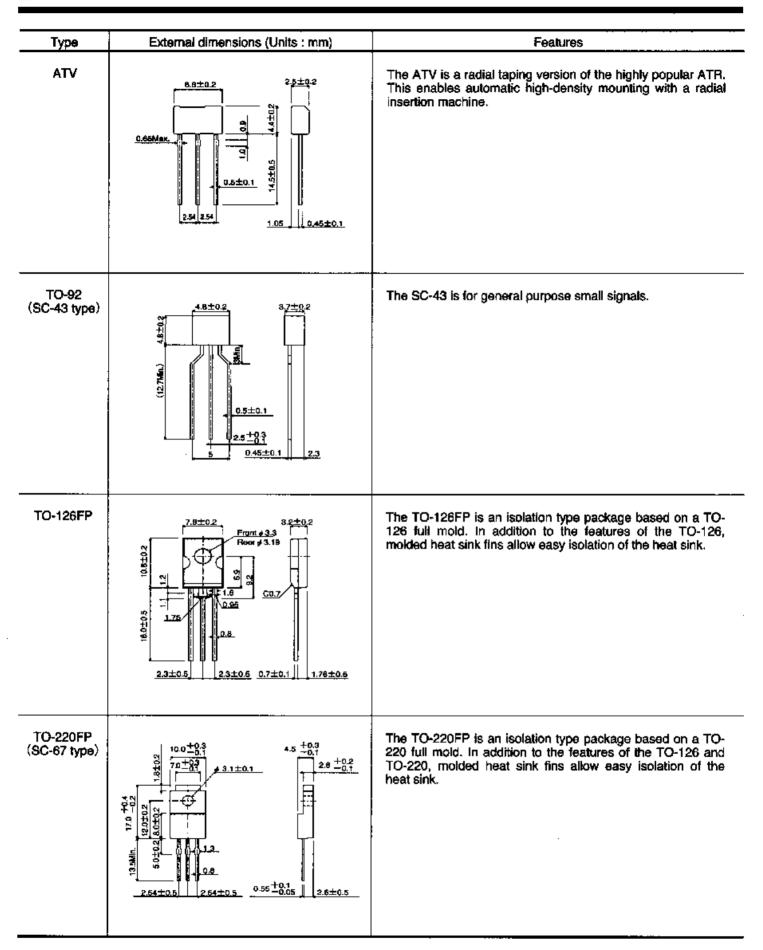


Туре	External dimensions (Units : mm)	Features
UMT5 SC-88A type	2.0±0.2 1.3±0.1 0.65 0.85 0.7 0.005 0.15±0.06 2.0±0.1 0.005 0.15±0.06	The UMT5 consists of two connected transistors or digital transistors in a UMT3 (SC-70) package. The mounting area can be reduced by 50% compared to the UMT3 and the internal circuitry is completed, making this package ideal for high density mounting at half the assembly cost.
UMT6 SC-88 type	2.0±0.2 1.3±0.1 0.65 0.65 0.7 0.7 0.7 0.7 0.7 0.7 0.7 0.7	The UMT6 consists of two independent transistors or two independent digital transistors in a UMT (SC-70) package. The mounting area and mounting cost can be reduced by 50% compared to the UMT3, and the two transistors are independent to allow free configuration of a high density circuit.

<ul> <li>Types and features of leaded package</li> </ul>	atures of leaded packages
--	---------------------------

Туре	External dimensions (Units : mm)	Features
SPT (SC-72 type)	2±0.2  2±0.2  0.45+0.15  0.45+0.05  0.46+0.15  0.46+0.05	The SPT is a smaller version of the conventional TO-92 type. The body size (3×4×2 mm³) has been reduced to 1/4 that of the TO-92 (5×5×4 mm³). The SPT is available on tape for automatic insertion, and less space is occupied on the printed circuit board than the TO-92. Reliability is the same as the TO-92.
FTR	0.85±0.1 0.85±0.1 0.85±0.1 0.45±0.1	SIL type with a height of 3.4 mm and a lead pitch of 2.54 mm.
FTL	0.65Max 0.65Max 0.55±0.1 0.5±0.1 0.45±0.1	The FTL is a radial taping version of the highly popular FTR. This enables automatic high-density mounting with a radial insertion machine.
ATR (SC-71 type)	0.65 0.4 0.65 0.4 0.65 0.4 0.65 0.4 0.65 0.4 0.45 0.1	SC-71type with a height of 4.4 mm and a Pc=1W type.

Transistors Packages



Туре	External dimensions (Units : mm)	Features
TO-220FN	10.0 +0.3 4.6 +0.3 2.8 +0.2 2.8 +0.2 2.0 +	The TO-220FN features the same performance as the TO-220FP with approximately 2 mm tess height, allowing the design of slimmer devices. Furthermore, the elimination of support pins in the fin (collector electrode) solves short-circuiting problems with neighboring components and the chassis.  To make the height to the installation hole the same as the TO-220FP, it can be replaced as is from the TO-220FP.